

L Number	Hits	Search Text	DB	Time stamp
3	663	257/378.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/25 11:10
4	559	257/434.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/25 11:14
5	358	257/556.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/25 11:14
6	392	257/557.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/25 11:18
7	206	257/560.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/25 11:24
8	139	257/563.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/25 11:26
9	105	257/564.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/25 11:26
-	7516	semiconductor and ((emitter and base) or (source and drain)) and (gate with (circular or anular or surround\$4))	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 14:35
-	3126	(semiconductor and ((emitter and base) or (source and drain)) and (gate with (circular or anular or surround\$4))) and (gate with polysilicon)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 14:35
-	698	semiconductor and ((emitter and base) and collector) and (gate with (circular or anular or surround\$4))	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 14:56
-	272	(semiconductor and ((emitter and base) and collector) and (gate with (circular or anular or surround\$4))) and (gate with polysilicon)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 14:57
-	409	(semiconductor and ((emitter and base) and collector) and (gate with (circular or anular or surround\$4))) and (gate with emitter)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 14:35
-	168	((semiconductor and ((emitter and base) and collector) and (gate with (circular or anular or surround\$4))) and (gate with polysilicon)) and (gate with emitter)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 14:36
-	109	((semiconductor and ((emitter and base) and collector) and (gate with (circular or anular or surround\$4))) and (gate with polysilicon)) and (gate with emitter) and gate.ab.	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 15:01
-	34	((semiconductor and ((emitter and base) and collector) and (gate with (circular or anular or surround\$4))) and (gate with polysilicon)) and (gate with emitter) and gate.ab.) and (emitter with contact) and (self-aligned or (self adj aligned))	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 14:38
-	17	5717241.URPN.	USPAT	2004/06/24 14:46
-	158	semiconductor and ((emitter and base) and collector) and (gate with (circular or anular or surround\$4 or around)) and (lateral with bipolar)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 15:03

-	78	(semiconductor and ((emitter and base) and collector) and (gate with (circular or anular or surround\$4 or around)) and (lateral with bipolar)) and (gate with polysilicon)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 14:57
-	50	((semiconductor and ((emitter and base) and collector) and (gate with (circular or anular or surround\$4 or around)) and (lateral with bipolar)) and (gate with polysilicon)) and gate.ab.	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 15:02
-	0	((semiconductor and ((emitter and base) and collector) and (gate with (circular or anular or surround\$4 or around)) and (lateral with bipolar)) and (gate with polysilicon)) and gate.ab.) and (gate with anular)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 15:04
-	172	semiconductor and ((emitter and base) and collector) and (gate with (circular or anular or annular or surround\$4 or around)) and (lateral with bipolar)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 15:04
-	29	(semiconductor and ((emitter and base) and collector) and (gate with (circular or anular or annular or surround\$4 or around)) and (lateral with bipolar)) and (gate with annular)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 15:24
-	2	("5717241").PN.	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 15:24
-	5	("4344081"   "4669177"   "4800415"   "5250826"   "5498885").PN.	USPAT	2004/06/24 15:25
-	28	4669177.URPN.	USPAT	2004/06/24 15:29